BLP15M7160P

Power LDMOS transistor

AMPLEON

Rev. 5 — 8 January 2016

Product data sheet

1. Product profile

1.1 General description

A 160W LDMOS RF power transistor for broadcast transmitter and industrial applications. The transistor is suitable for the frequency range HF to 1500 MHz. The excellent ruggedness and broadband performance of this device makes it ideal for digital applications.

Table 1. Typical performance

RF performance at T_h = 25 $^{\circ}$ C in a common source test circuit.

| Test signal | f | V _{DS} | I _{Dq} | P _{L(AV)} | P _{L(M)} | G _p | η_D |
|-----------------|-------|-----------------|-----------------|--------------------|-------------------|----------------|----------|
| | (MHz) | (V) | (mA) | (W) | (W) | (dB) | (%) |
| pulsed, class-B | 860 | 28 | 100 | - | 160 | 20 | 62 |

1.2 Features and benefits

- Integrated ESD protection
- Excellent ruggedness
- High power gain
- High efficiency
- Excellent reliability
- Easy power control
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Communication transmitter applications in the HF to 1500 MHz frequency range
- Industrial applications in the HF to 1500 MHz frequency range
- Single product Doherty applications

2. Pinning information

Table 2. Pinning

All pins must be connected for correct operation and to prevent damage to the device.

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------|--------------------|-----------------|
| 1 | gate 1 | 4 2 | |
| 2 | gate 2 | 4 3 | 4 |
| 3 | drain 2 | | 1_ |
| 4 | drain 1 | pin 1 index | 5 |
| 5 | source [1] | 1 2 | 3 aaa-006617 |

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Package | Package | | | |
|-------------|---------|---|-----------|--|--|
| | Name | Description | Version | | |
| BLP15M7160P | HSOP4F | plastic, heatsink small outline package; 4 leads (flat) | SOT1223-2 | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|-----|------|------|
| V_{DS} | drain-source voltage | | - | 65 | V |
| V_{GS} | gate-source voltage | | -6 | +11 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | [1] | - | 225 | °C |

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|-------------------------|--|--|-----|------|
| $R_{\text{th(j-case)}}$ | thermal resistance from junction to case | $T_{case} = 80 ^{\circ}C; P_{L} = 160 W$ [1] | 0.5 | K/W |

[1] R_{th(j-case)} is measured under RF conditions.

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C per section; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|----------------------------------|--|------|------|------|------|
| V _{(BR)DSS} | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 0.9 \text{ mA}$ | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | V_{DS} = 10 V; I_{D} = 90 mA | 1.5 | 1.86 | 2.3 | V |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | -1.4 | - | +1.4 | μΑ |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$ | 15 | 16 | - | А |
| I _{GSS} | gate leakage current | V _{GS} = 11 V; V _{DS} = 0 V | - | - | 140 | nA |
| g _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 3.15 A | - | 6 | - | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 3.15 \text{ A}$ | - | 0.2 | - | Ω |

Table 7. AC characteristics

 T_i = 25 °C per section; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|----------------------|--|-----|-----|-----|------|
| C _{iss} | input capacitance | $V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}; f = 1 \text{ MHz}$ | - | 79 | - | pF |
| Coss | output capacitance | $V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}; f = 1 \text{ MHz}$ | - | 32 | - | pF |
| C _{rs} | feedback capacitance | V _{GS} = 0 V; V _{DS} = 28 V; f = 1 MHz | - | 1.5 | - | pF |

Table 8. RF characteristics

Test signal: pulsed CW; f = 860 MHz; RF performance measured at V_{DS} = 28 V; I_{Dq} = 100 mA; T_{case} = 25 °C; unless otherwise specified; in a class-B production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------|------------------|---------------------------|------|------|-----|------|
| G_p | power gain | P _{L(M)} = 160 W | 16.5 | 19.4 | - | dB |
| η_{D} | drain efficiency | P _{L(M)} = 160 W | 57.5 | 59.7 | - | % |

7. Test information

7.1 Ruggedness in class-AB operation

The BLP15M7160P is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; f = 860 MHz at rated load power.

7.2 Demo circuit information

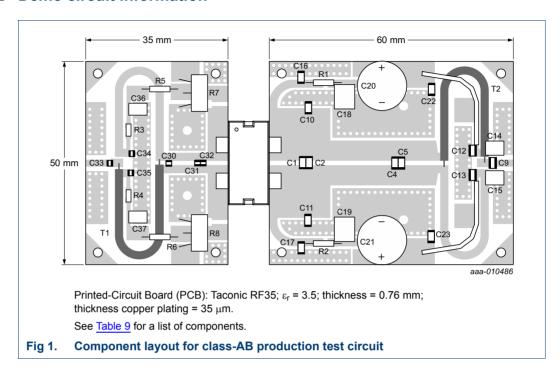


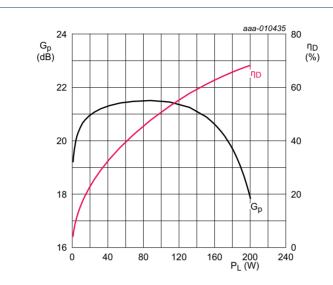
Table 9. List of components

For test circuit see Figure 1.

| Component | Description | Value | Remarks |
|---------------|-----------------------------------|--------------|-----------------------|
| C1, C2 | multilayer ceramic chip capacitor | 5.6 pF | ATC800B |
| C4, C5 | multilayer ceramic chip capacitor | 4.7 pF | ATC800B |
| C9 | multilayer ceramic chip capacitor | 100 pF | ATC180R |
| C10, C11 | multilayer ceramic chip capacitor | 10 pF | ATC800B |
| C12, C13 | multilayer ceramic chip capacitor | 100 pF | ATC180R |
| C14, C15 | multilayer ceramic chip capacitor | 4.7 μF, 50 V | TDK |
| C16, C17 | multilayer ceramic chip capacitor | 100 pF | ATC800B |
| C18, C19 | multilayer ceramic chip capacitor | 10 μF | TDK |
| C20, C21 | electrolytic capacitor | 470 μF, 63 V | |
| C22, C23 | multilayer ceramic chip capacitor | 1 nF | ATC800B |
| C30 | multilayer ceramic chip capacitor | 33 pF | ATC800A |
| C31 | multilayer ceramic chip capacitor | 10 pF | ATC800A |
| C32 | multilayer ceramic chip capacitor | 11 pF | ATC800A |
| C33, C34, C35 | multilayer ceramic chip capacitor | 91 pF | ATC800A |
| C36, C37 | electrolytic capacitor | 4.7 μF, 50 V | |
| T1 | semi rigid coax | 25 Ω | Micro-Coax UT-090C-25 |
| T2 | semi rigid coax | 25 Ω | Micro-Coax UT-090C-25 |
| R1, R2 | resistor | 10 Ω | Vishay MRS25 |
| R3, R4 | resistor | 5.6 Ω | SMD 1206 |
| R5, R6 | resistor | 100 Ω | Vishay MRS25 |
| R7, R8 | potentiometer | 10 kΩ | Bourns |

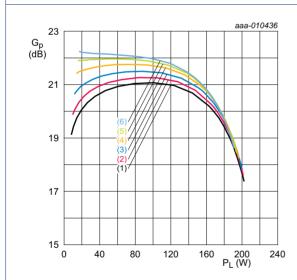
7.3 Graphical data

7.3.1 1-Tone pulsed



 V_{DS} = 28 V; I_{Dq} = 200 mA; f = 860 MHz.

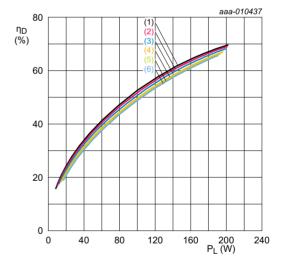
Fig 2. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 28 V; f = 860 MHz.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$
- (5) $I_{Dq} = 600 \text{ mA}$
- (6) $I_{Dq} = 800 \text{ mA}$

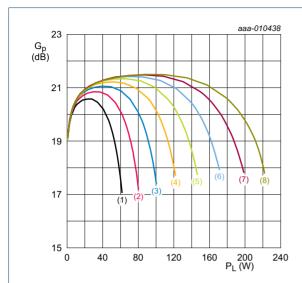
Fig 3. Power gain as a function of output power; typical values



V_{DS} = 28 V; f = 860 MHz.

- (1) $I_{Dq} = 50 \text{ mA}$
- (2) $I_{Dq} = 100 \text{ mA}$
- (3) $I_{Dq} = 200 \text{ mA}$
- (4) $I_{Dq} = 400 \text{ mA}$
- (5) $I_{Dq} = 600 \text{ mA}$
- (6) $I_{Dq} = 800 \text{ mA}$

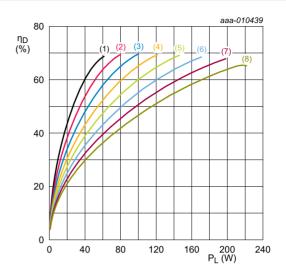
Fig 4. Drain efficiency as a function of output power; typical values



 $I_{Da} = 200 \text{ mA}$; f = 860 MHz.

- (1) $V_{DS} = 16 V$
- (2) $V_{DS} = 18 \text{ V}$
- (3) $V_{DS} = 20 \text{ V}$
- (4) $V_{DS} = 22 V$
- (5) $V_{DS} = 24 \text{ V}$
- (6) $V_{DS} = 26 \text{ V}$
- (7) $V_{DS} = 28 \text{ V}$
- (8) $V_{DS} = 30 \text{ V}$

Fig 5. Power gain as a function of output power; typical values



 I_{Dq} = 200 mA; f = 860 MHz.

- (1) $V_{DS} = 16 V$
- (2) $V_{DS} = 18 V$
- (3) $V_{DS} = 20 \text{ V}$
- (4) $V_{DS} = 22 V$
- (5) $V_{DS} = 24 V$
- (6) $V_{DS} = 26 V$
- (7) $V_{DS} = 28 \text{ V}$
- (8) $V_{DS} = 30 \text{ V}$

Fig 6. Drain efficiency as a function of output power; typical values

8. Package outline

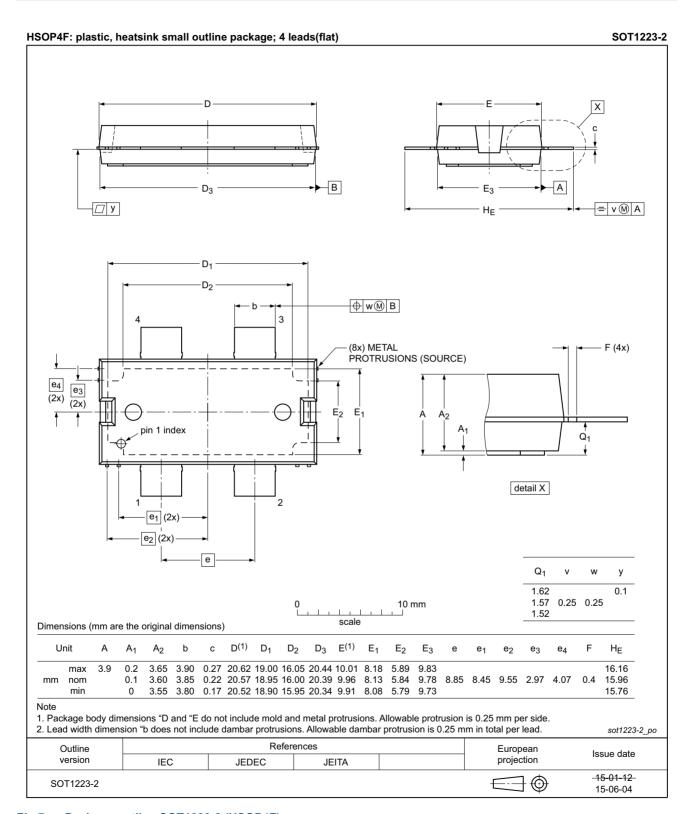


Fig 7. Package outline SOT1223-2 (HSOP4F)

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

| Acronym | Description | |
|---------|--|--|
| CW | Continuous Wave | |
| ESD | lectroStatic Discharge | |
| HF | High Frequency | |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor | |
| MTF | Median Time to Failure | |
| SMD | Surface Mounted Device | |
| VSWR | Voltage Standing-Wave Ratio | |

11. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|-----------------|------------------|--|----------------------|-----------------|--|--|
| BLP15M7160P v.5 | 20160108 | Product data sheet | - | BLP15M7160P v.4 | | |
| Modifications | Table 3 on pag | <u>Table 3 on page 2</u> : table updated | | | | |
| | • Figure 7 on pa | ge 7: package outline changed | from SOT1223-1 to So | OT1223-2 | | |
| BLP15M7160P v.4 | 20150901 | Product data sheet | - | BLP15M7160P v.3 | | |
| BLP15M7160P v.3 | 20150209 | Product data sheet | - | BLP15M7160P v.2 | | |
| BLP15M7160P v.2 | 20140610 | Product data sheet | - | BLP15M7160P v.1 | | |
| BLP15M7160P v.1 | 20140110 | Objective data sheet | - | - | | |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
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